

Full Material Declaration for attached parts list

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Diotec Semiconductor AG

DUNS number: 330866844

-, Kreuzmattenstr. 4, Heitersheim, B.-W., 79423, Germany

Declarations authorised by:

Udo Steinebrunner, Product Manager, -

Declaration effective from: 10 September 2010 [Approved on 15 June 2016, 09:36 GMT]

Materials and substances

Use/Location	Material group	% w/w of material in the part	Substances in the material	CAS Number	% w/w of substance in the material
Chip (die)	Other inorganic materials	0.06000%	Nickel	7440-02-0	1.00000%
			Gold	7440-57-5	11.50000%
			Dow corning 3110	63394-02-5	25.00000%
			Silicon	7440-21-3	62.50000%
Die attach	Sn-Pb solder	0.03000%	Silver	7440-22-4	2.50000%
			Tin	7440-31-5	5.00000%
			Lead	7439-92-1	92.50000%
Encapsulation	EP (Epoxy resin)	41.58000%	Carbon black	1333-86-4	0.30000%
			ANTIMONY TRIOXIDE	1309-64-4	0.80000%
			Tetrabromobisphenol A	79-94-7	0.99000%
			Epoxy resin 89	26335-32-0	27.61000%
			Quartz sand	60676-86-0	70.30000%
Leadfinish	Tin plating	0.48000%	Tin	7440-31-5	100.00000%
Leadframe	Copper (e.g. copper amounts in cable harnesses)	57.85000%	Copper	7440-50-8	100.00000%

Attached parts list

Part number	Part name	Part Mass	Part Mass UoM
TO-263AB	Diode/Transistor Power	1.8	g